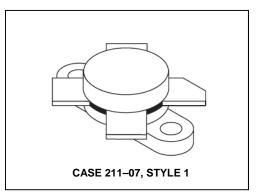


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Designed for high gain driver and output linear amplifier stages in 1.5 to 30 MHz HF/SSB equipment.

- Specified 28 V, 30 MHz characteristics Output power = 25 W (PEP) Minimum gain = 22 dB Efficiency = 35%
- Intermodulation distortion @ 25 W (PEP) —IMD = -30 dB (max)
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Class A and AB characterization
- BLX 13 equivalent

Product Image



MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|------------------|-------------|---------------|
| Collector–Emitter Voltage | V _{CEO} | 35 | Vdc |
| Collector-Base Voltage | V _{CBO} | 65 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 4.0 | Vdc |
| Collector Current — Continuous | Ic | 3.0 | Adc |
| Withstand Current — 5 s | _ | 6.0 | Adc |
| Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C | P _D | 70 0.4 | Watts W/°C |
| Storage Temperature Range | T _{stg} | -65 to +150 | °C |

THERMAL CHARACTERISTICS

Commitment to produce in volume is not guaranteed.

| Characteristic | Symbol | Max | Unit |
|--------------------------------------|------------------|-----|------|
| Thermal Resistance, Junction to Case | R _{eJC} | 2.5 | °C/W |

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

| Symbol | Min | Тур | Max | Unit |
|----------------------|----------------------------------|--|--|--|
| | • | | • | |
| V _{(BR)CEO} | 35 | _ | _ | Vdc |
| V _{(BR)CBO} | 65 | _ | _ | Vdc |
| V _{(BR)EBO} | 4.0 | _ | _ | Vdc |
| Ices | _ | _ | 10 | mAdc |
| | V(BR)CEO V(BR)CBO V(BR)EBO | V _{(BR)CEO} 35 V _{(BR)CBO} 65 V _{(BR)EBO} 4.0 | V _{(BR)CEO} 35 — V _{(BR)CBO} 65 — V _{(BR)EBO} 4.0 — | V(BR)CEO 35 — — V(BR)CBO 65 — — V(BR)EBO 4.0 — — |

NOTE:

(continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

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MRF426



The RF Line NPN Silicon Power Transistor 25W(PEP), 30MHz, 28V

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| ELECTRICAL CHARACTERISTICS — continued | (T _C = 25°C unless otherwise noted.) |
|--|---|
|--|---|

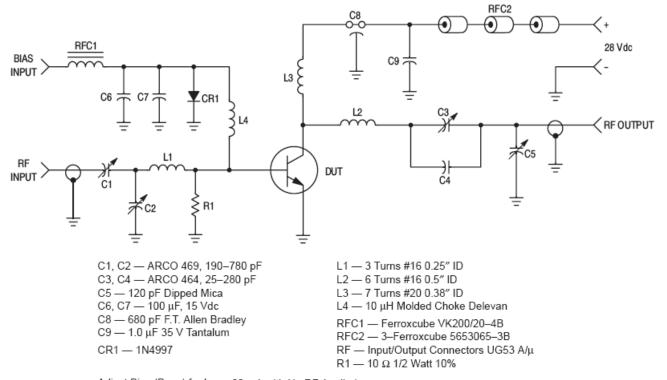
| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|---|--------------------------------|--------------------|-----|------|
| ON CHARACTERISTICS | • | • | | | |
| DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc) | h _{FE} | 10 | 35 | _ | _ |
| DYNAMIC CHARACTERISTICS | • | • | • | | |
| Output Capacitance (V _{CB} = 30 Vdc, I _E = 0, f = 1.0 MHz) | C _{ob} | _ | 60 | 80 | pF |
| FUNCTIONAL TESTS (SSB) | • | • | | | |
| Common–Emitter Amplifier Gain (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA) | G _{PE} | 22 | 25 | _ | dB |
| Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA) | η | 35 | _ | _ | % |
| Intermodulation Distortion (2) (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA) | IMD _(d3) | _ | -35 | -30 | dB |
| Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 25 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 25 mA, VSWR 30:1 at All Phase Angles) | Ψ | No Degradation in Output Power | | | |
| CLASS A PERFORMANCE | | | | | |
| Intermodulation Distortion (2) and Power Gain (V _{CC} = 28 Vdc, P _{out} = 8.0 W (PEP), f1 = 30 MHz, f2 = 30.001 MHz, I _{CQ} = 1.2 Adc) | G _{PE} IMD _(d3) IMD _(d5) | | 23.5 -40 -55 | | dB |

NOTE:

2. To Mil-Std-1311 Version A, Test Method 2204B, Two Tone, Reference each Tone.



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Adjust Bias (Base) for I_{CQ} = 20 mA with No RF Applied

Figure 1. 30 MHz Linear Test Circuit

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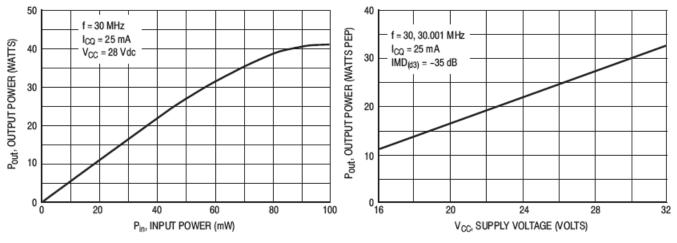


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Supply Voltage

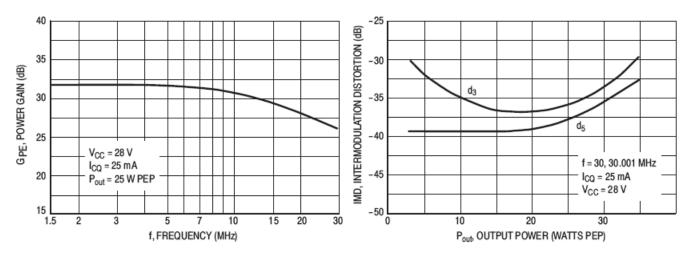


Figure 4. Power Gain versus Frequency

Figure 5. Intermodulation Distortion versus Output Power

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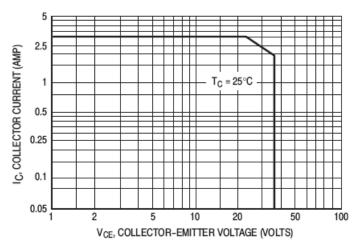


Figure 6. DC Safe Operating Area

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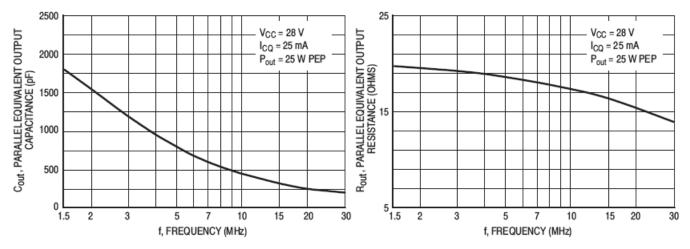


Figure 7. Output Capacitance versus Frequency

Figure 8. Output Resistance versus Frequency

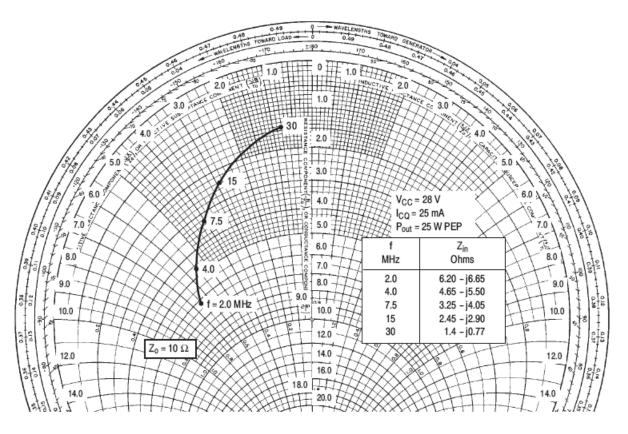


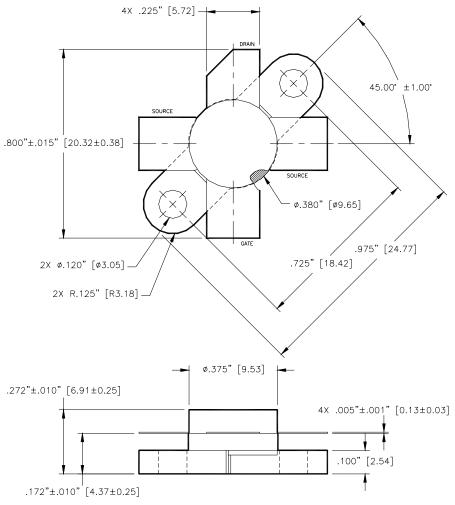
Figure 9. Series Equivalent Input Impedance

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Unless otherwise noted, tolerances are inches $\pm .005$ " [millimeters ± 0.13 mm]

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